## Product specification

**BYV72EW** series

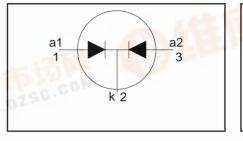
#### Rectifier diodes ultrafast, rugged

#### FEATURES

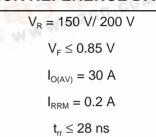
- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

#### SYMBOL

WWW.DZSC.



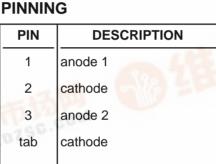
### QUICK REFERENCE DATA



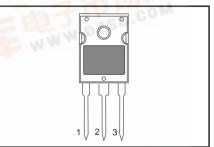
#### GENERAL DESCRIPTION

Dual, ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYV72EW series is supplied in the conventional leaded SOT429 (TO247) package.



#### SOT429 (TO247)



#### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
		BYV72EW		-150	-200	
V <sub>RRM</sub>	Peak repetitive reverse voltage		1.1	150	200	V
VRWM	Crest working reverse voltage		-	150	200	V
V <sub>R</sub>	Continuous reverse voltage	T <sub>mb</sub> ≤ 144°C	-	150	200	V
I <sub>O(AV)</sub>	Average rectified output current (both diodes conducting) <sup>1</sup>	square wave δ = 0.5; T <sub>mb</sub> ≤ 104 °C	-	3	0	A
FRM	Repetitive peak forward current	t = 25 μs; δ = 0.5; T <sub>mb</sub> ≤ 104 °C	-	3	0	A
I <sub>FSM</sub>	Non-repetitive peak forward	t = 10  ms	-	15	50	A
-FSM	current per diode	t = 8.3 ms sinusoidal; with reapplied	-		50	A
I <sub>RRM</sub>	Repetitive peak reverse current	$V_{\text{RWM(max)}} t_p = 2 \ \mu\text{s}; \ \delta = 0.001$	E		.2	A
I <sub>RSM</sub>	Non-repetitive peak reverse current per diode	t <sub>p</sub> = 100 μs	1	0	.2	A
<u></u> stg	Storage temperature		-40	15	50	°C
Ti	Operating junction temperature	COM	-	15	50	°C

1 Neglecting switching and reverse current losses.

#### ESD LIMITING VALUE

f.dzsc.com

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>c</sub>	Electrostatic discharge capacitor voltage	Human body model; C = 250 pF; R = 1.5 k $\Omega$	-	8	kV

#### Product specification

**BYV72EW** series

# Rectifier diodes ultrafast, rugged

#### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-mb</sub> R <sub>th j-a</sub>	mounting base	per diode both diodes conducting in free air		- - 45	2.4 1.4 -	K/W K/W K/W

#### **ELECTRICAL CHARACTERISTICS**

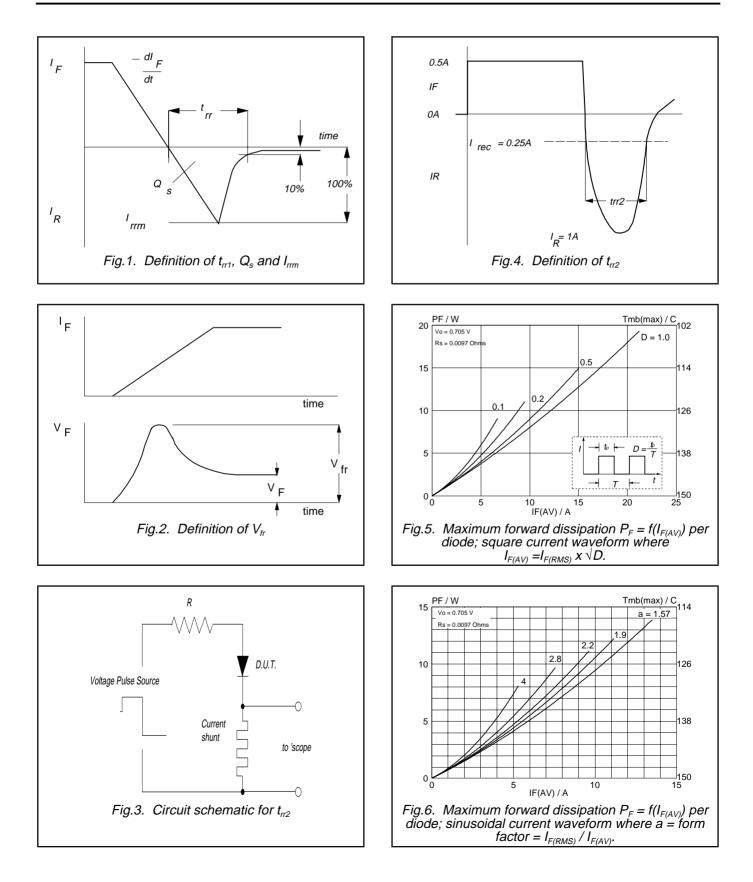
characteristics are per diode at  $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	Forward voltage	I <sub>F</sub> = 15 A; T <sub>i</sub> = 150°C	-	0.83	0.90	V
	-	$I_{\rm F} = 15  {\rm A}^{-1}$	-	0.95	1.05	V
		$I_{\rm F} = 30  {\rm A}$	-	1.00	1.20	V
I <sub>R</sub>	Reverse current	$\dot{V}_{R} = V_{RWM}; T_{i} = 100 \ ^{\circ}C$	-	0.5	1	mA
		$V_{\rm R} = V_{\rm RWM}$	-	10	100	μA
Q <sub>s</sub>	Reverse recovery charge	$I_{\rm F} = 2 \text{ A}; V_{\rm R} \ge 30 \text{ V}; -dI_{\rm F}/dt = 20 \text{ A}/\mu \text{s}$	-	6	15	'nC
t <sub>rr1</sub>	Reverse recovery time	$I_{\rm F} = 1 \text{ A}; V_{\rm R} \ge 30 \text{ V};$	-	20	28	ns
		-dI <sub>F</sub> /dt = 100 A/μs				
t <sub>rr2</sub>	Reverse recovery time	$I_{\rm F} = 0.5 \text{ A to } I_{\rm R} = 1 \text{ A}; I_{\rm rec} = 0.25 \text{ A}$	-	13	22	ns
V <sub>fr</sub>	Forward recovery voltage	$I_{F} = 1 \text{ A}; \text{ d}_{F}/\text{d}t = 10 \text{ A}/\mu s$	-	1	-	V

# Rectifier diodes ultrafast, rugged

## Product specification

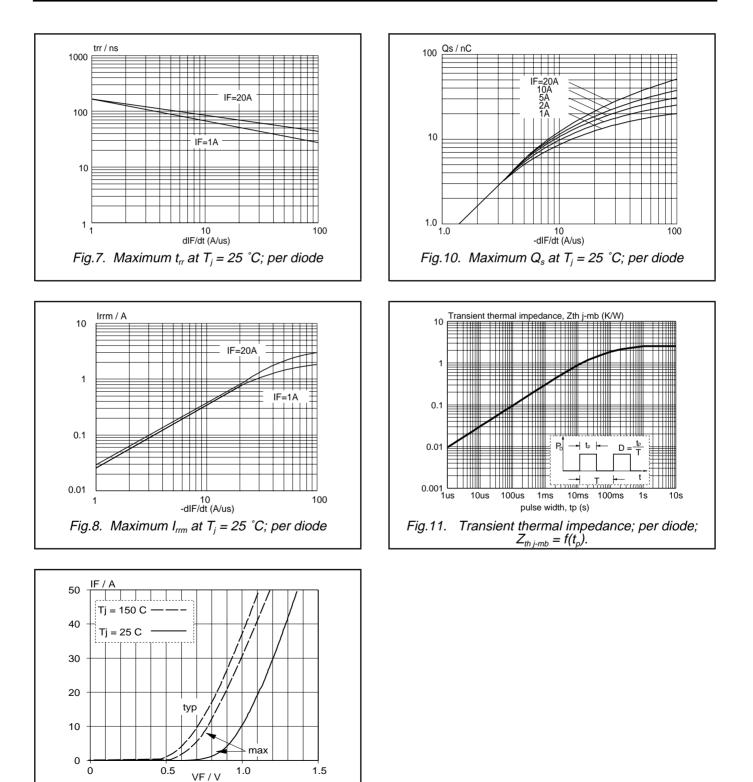
#### BYV72EW series

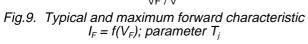


Product specification

**BYV72EW** series

# Rectifier diodes ultrafast, rugged



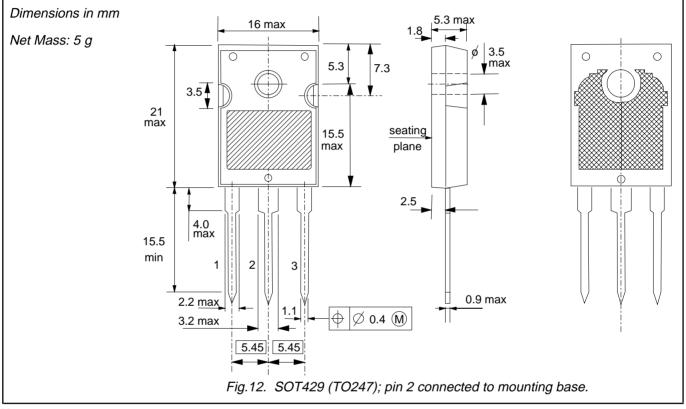


### **Rectifier diodes** ultrafast, rugged

### **BYV72EW** series

**Product specification** 

### **MECHANICAL DATA**



#### Notes

Refer to mounting instructions for SOT429 envelope.
Epoxy meets UL94 V0 at 1/8".

Product specification

Rectifier diodes ultrafast, rugged

#### BYV72EW series

#### DEFINITIONS

Data sheet status				
Objective specification	Dbjective specification This data sheet contains target or goal specifications for product development.			
Preliminary specification	eliminary specification This data sheet contains preliminary data; supplementary data may be published later			
Product specification	specification This data sheet contains final product specifications.			
Limiting values				
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.				
Application information				
Where application information is given, it is advisory and does not form part of the specification.				
© Philips Electronics N.V. 1998				
All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.				

The information presented in this document does not form part of any quotation or contract, it is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.

#### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.